

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/698,466	11/03/2003	Куо Но Мооп	049128-5048-01	1849	
9629	7590 06/22/2005		EXAMINER		
MORGAN LEWIS & BOCKIUS LLP			GUERRERO, MARIA F		
	YLVANIA AVENUE N ON, DC 20004	W	ART UNIT	ART UNIT PAPER NUMBER	
	•		2822		
				DATE MAILED: 06/22/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)				
	10/698,466	MOON ET AL.	(In			
Office Action Summary	Examiner	Art Unit				
	Maria Guerrero	2822				
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence add	ress			
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply - If NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	6(a). In no event, however, may a reply be tim within the statutory minimum of thirty (30) days ill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this com D (35 U.S.C. § 133).	nmunication.			
Status						
1) Responsive to communication(s) filed on 13 Oc	ctober 2004.					
	action is non-final.					
	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims						
4) ☐ Claim(s) 19-27 is/are pending in the application 4a) Of the above claim(s) is/are withdraw 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 19-27 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/or	n from consideration.					
Application Papers						
9) The specification is objected to by the Examiner 10) The drawing(s) filed on is/are: a) access Applicant may not request that any objection to the of Replacement drawing sheet(s) including the correction	epted or b) objected to by the Edrawing(s) be held in abeyance. See	e 37 CFR 1.85(a).	R 1.121(d).			
11) The oath or declaration is objected to by the Ex	aminer. Note the attached Office	Action or form PTC	D-152.			
Priority under 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the priority application from the International Bureau * See the attached detailed Office action for a list of	have been received. have been received in Application ity documents have been received (PCT Rule 17.2(a)).	on No. <u>10/005,867</u> . ed in this National S	itage			
Attachment(s)						
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal P 6) Other:	ite	152)			

DETAILED ACTION

1. This Office Action is in response to the preliminary amendment filed November 3, 2003.

Status of Claims

2. Claims 1-18 are canceled. Claims 19-27 are pending.

Information Disclosure Statement

3. The information disclosure statements filed November 3, 2003 and October 13, 2003 have been considered.

Priority

4. Acknowledgment is made of applicant's claim for foreign priority under 35 U.S.C. 119(a)-(d). The certified copy has been filed in parent Application No. 10/005,867, filed on December 7, 2001.

Specification

5. The lengthy specification has not been checked to the extent necessary to determine the presence of all possible minor errors. Applicant's cooperation is requested in correcting any errors of which applicant may become aware in the specification.

Art Unit: 2822

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

6. Claims 19-27 are rejected under 35 U.S.C. 103(a) as being unpatentable over Applicant admitted prior art in view of Rho et al. (US 6,057,896).

Applicant admitted prior art shows forming an organic protective film on a substrate, forming a first alignment film, detecting at least one irregularity on the first alignment film, eliminating the first alignment film and forming a second alignment film (Figs. 4-5, page 5-6). Applicant admitted prior art discloses eliminating the first alignment film includes dry etching rework processing using at least one compound gas of SF6, O2, O2+Cl2 and CF4 (Figs. 4-5, page 5).

Furthermore, Applicant admitted prior art describes forming a gate line and a gate electrode on the substrate, forming a gate insulating film on the gate line, the gate electrode and the substrate (Figs. 1-3E). Applicant admitted prior art teaches forming a semiconductor layer on the gate insulating film and forming a data line, a source electrode and a drain electrode on the gate insulating film (Fig. 1-3E). Applicant admitted prior art shows forming a pixel electrode to overlap at least one of the data line and the gate line (Figs. 1-2, pages 3-4).

Applicant admitted prior art does not specifically show forming a silicon nitride layer on the organic protective film. However, Rho et al. teaches forming a silicon nitride layer on the organic protective film in order to better protect the lower layer (Figs. 3-11, col. 6, lines 50-64, col. 7, lines 1-5, col. 9, lines 62-67, col. 10, lines 1-5, 25-35). Rho et al. shows the silicon nitride layer having a different etch rate compared to the organic protective film and compared to an organic film formed on the silicon nitride layer (Figs. 8-11, col. 5, lines 59-62, col. 7, lines1-5).

Regarding the specific concentration claimed, one of ordinary skill in the art would have found it prima facie obvious at the time of the invention to select the concentration merely by following the teachings of the reference. In this regard, it is well settled that it is not inventive to determine (by mere routine experimentation) the optimum values of a result-effective variable. In re Peterson, 315 F.3d 1325, 1330, 65 USPQ2d 1379, 1382 (Fed. Cir, 2003)("The normal desire of scientist or artisans to determine where in a disclosed set of percentage ranges is the optimum combination of percentages."); In re Boesch, 617 F.2d 272, 276, 205 USPQ 215, 219 (CCPA 1980)

("Discovery of an optimum value of a result effective variable in a known process is ordinarily within the skill of the art."); In re aller 220 F. 2d 454, 456, 105 USPQ 233, 235, (CCPA 1955)("Where the general conditions of a claim are discloses in the prior art, it is not inventive to discover the optimum or workable ranges by routine experimentation.").

Therefore, it would have been obvious to a person of ordinary skill in the art at the time of the invention to modify Applicant admitted prior art by including the step of forming the silicon nitride as taught by Rho et al. in order to better protect the device and to avoid leakage current (Rho et al., 60-63).

Double Patenting

7. The Non-Statutory Double Patenting Rejection in view of US Patent No. 6,844,906 has not been applied because this is a divisional application as a result of a restriction requirement made in a parent application 10/005,867 (US 6,683,668). Generally, a double patenting rejection is not permitted where the claimed subject matter is presented in a divisional application as a result of a restriction requirement made in a parent application under 35 U.S.C. 121.

Conclusion

8. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Maria Guerrero whose telephone number is 571-272-1837.

Application/Control Number: 10/698,466 Page 6

Art Unit: 2822

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Amir Zarabian can be reached on 571-272-1852. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

June 16, 2005

MARIA F. GUERRERO
PRIMARY EXAMINE